Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	10/622350	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/11 17:41
S2	1506	(257/295).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:41
S3	1559	(438/3).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:50
S4	0	(first adj magnetic adj layer near5 second adj magnetic adj layer) near5 nonmagnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:57
S5	0	(first adj magnetic adj layer with second adj magnetic adj layer) near5 nonmagnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:54
S6	0	(first adj magnetic adj layer near5 second adj magnetic adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:53
S7	2665	(first adj magnetic adj layer with second adj magnetic adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:53
S8	182	S7 with nonmagnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:54
S9	134	S8 and thick$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 08:01

S10	21	S8 with thick$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:54
S11	21	S10 and first adj magnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:58
S12	21	S11 and second adj magnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:00
S13	50	parallel near3 zero near field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 17:59
S14	0	S12 and S13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:00
S15	0	S11 and S13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:01
S16	4	S10 and parallel near3 field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:21
S17	46501	MRAM and A(first adj magnetic adj layer near5 second adj magnetic adj layer) near5 nonmagnetic adj layer AP	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:21
S18	1	mram and 'avap'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:24
S19	0	mram and diferent adj thickness	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:24

S20	43	mram and different adj thickness	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 18:42
S21	4	("6567246").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 19:21
S22	2	("6545906").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 19:21
S23	2665	(first adj magnetic adj layer with second adj magnetic adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 07:55
S24	182	S23 with nonmagnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 07:56
S25	56	MRAM and S24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 13:41
S26	48	S25 and thick$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 14:12
S27	28	S26 and (nonmagnetic non-magnetic insulat$3) near5 (Ru Os Re Rh Mo Ir Cr Cu)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 13:11
S28	13	S27 and coupl$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 12:56
S29	0	S27 and parallel near coupl$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 12:57

S30	2	S27 and parallel near3 coupl$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 12:57
S31	50	parallel near3 zero near field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:42
S32	3	S31 and (nonmagnetic non-magnetic insulat$3) near5 (Ru Os Re Rh Mo Ir Cr Cu)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:13
S33	0	S24 and S32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 13:12
S34	1	S23 and S32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 13:12
S35	2	MRAM and S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:47
S36	1	S26 and S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 14:13
S37	2	S24 and S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 14:13
S38	1	memory adj cell with S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:43
S39	2	memory adj cell and S31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:33

S40	128	parallel near5 zero near field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:46
S41	1	memory adj cell with S40	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:44
S42	171	parallel with zero near field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:44
S43	2	memory adj cell with S42	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:44
S44	5661	zero near field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:46
S45	103	MRAM and S44	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:47
S46	18	MRAM and S23 and S44	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 16:47
S47	10	S46 and (nonmagnetic non-magnetic insulat$3) near5 (Ru Os Re Rh Mo Ir Cr Cu)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 17:30
S48	5407	free adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 17:28
S49	5913	free adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 17:28

S50	2667	pinned adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 17:28
S51	4536	MRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 17:28
S52	477	S49 and S50 and S51	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 17:29
S53	0	S52 and S42	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/14 17:29
S54	147	S52 and (nonmagnetic non-magnetic insulat$3) near5 (Ru Os Re Rh Mo Ir Cr Cu)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 17:31
S55	18	S54 and S44	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/14 17:31
S56	50	parallel near3 zero near field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:13
S57	0	S56 and (nonmagnetic non-magnetic insulat$3) near5 Ru	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:15
S58	0	S56 and (nonmagnetic non-magnetic insulat$3) near5 (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:15
S59	0	S56 and (nonmagnetic non-magnetic insulat$3) with (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:15

S60	2779	(nonmagnetic non-magnetic insulat$3) with (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:15
S61	1334	(nonmagnetic non-magnetic insulat$3) near5 (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:16
S62	832	(nonmagnetic non-magnetic insulat$3) near3 (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:16
S63	478	(nonmagnetic non-magnetic insulat$3) near2 (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:16
S64	144	(nonmagnetic non-magnetic insulat$3) near (Ru ruthenium)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:26
S65	46553	MRAM and A(first adj magnetic adj layer near5 second adj magnetic adj layer) near5 nonmagnetic adj layer AP	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:42
S66	19	S65 and S64	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:25
S67	0	(nonmagnetic non-magnetic insulat$3) near ((Ru ruthenium) with (dust$3 reduc$3 near3 coupling))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:27
S68	0	(nonmagnetic non-magnetic insulat$3) near ((Ru ruthenium)and (dust$3 reduc$3 near3 coupling))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:27
S69	34	(nonmagnetic non-magnetic insulat$3) near (Ru ruthenium) and (dust$3 reduc$3 near3 coupling)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 14:55

S70	3	S65 and S69	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:28
S71	42177	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) near5 nonmagnetic adj layer AP	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:42
S72	0	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) near5 nonmagnetic adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:44
S73	0	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) near5 (nonmagnetic adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:48
S74	0	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) and ((nonmagnetic non-magnetic) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/15 08:45
S75	0	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) with((nonmagnetic non-magnetic) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:45
S76	0	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) with ((nonmagnetic non-magnetic) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:46
S77	0	MRAM and (first adj magnetic adj layer near5 second adj magnetic adj layer) and ((nonmagnetic non-magnetic) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:48
S78	243	MRAM and (first adj magnetic adj layer and second adj magnetic adj layer) and ((nonmagnetic non-magnetic) adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:49
S79	3	S78 and S69	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:49

S80	5	(nonmagnetic non-magnetic insulat$3) near (Ru ruthenium) and (dust$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 08:50
S81	34	(nonmagnetic non-magnetic insulat$3) near (Ru ruthenium) and (dust$3 reduc$3 near3 coupling)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 14:55